RoHS

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Vishay General Semiconductor

# High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low V<sub>F</sub> = 0.59 V at I<sub>F</sub> = 5.0 A



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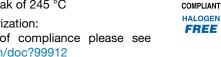
**DESIGN SUPPORT TOOLS** 



| PRIMARY CHARACTERISTICS |                               |  |  |  |
|-------------------------|-------------------------------|--|--|--|
| I <sub>F(AV)</sub>      | 10 A                          |  |  |  |
| V <sub>RRM</sub>        | 150 V                         |  |  |  |
| I <sub>FSM</sub>        | 120 A                         |  |  |  |
| $V_F$ at $I_F = 10$ A   | 0.69 V                        |  |  |  |
| T <sub>J</sub> max.     | 150 °C                        |  |  |  |
| Package                 | D <sup>2</sup> PAK (TO-263AB) |  |  |  |
| Circuit configuration   | Single                        |  |  |  |

## **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

#### Case: D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)                |                                   |             |      |  |
|---|-----------------------------------|-------------|------|--|
| PARAMETER   | SYMBOL                            | VB10150S    | UNIT |  |
| Maximum repetitive peak reverse voltage   | V <sub>RRM</sub>                  | 150         | V    |  |
| Maximum average forward rectified current (fig. 1)                                    | I <sub>F(AV)</sub>                | 10          | A    |  |
| Peak forward surge current 8.3 ms single half sine-wave<br>superimposed on rated load | I <sub>FSM</sub>                  | 120         | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )  | dV/dt                             | 10 000      | V/µs |  |
| Operating junction and storage temperature range                                      | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |  |

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                        |                         |                |      |      |      |
|---|------------------------|-------------------------|----------------|------|------|------|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL         | TYP. | MAX. | UNIT |
| Instantaneous forward voltage<br>per diode <sup>(1)</sup>                         | I <sub>F</sub> = 5.0 A | T <sub>A</sub> = 25 °C  | V <sub>F</sub> | 0.79 | -    | V    |
|   | I <sub>F</sub> = 10 A  |                         |                | 1.05 | 1.20 |      |
|   | I <sub>F</sub> = 5.0 A | T <sub>A</sub> = 125 °C |                | 0.59 | -    |      |
|   | I <sub>F</sub> = 10 A  |                         |                | 0.69 | 0.75 |      |
| Reverse current per diode <sup>(2)</sup>  | V <sub>R</sub> = 100 V | T <sub>A</sub> = 25 °C  | I <sub>R</sub> | 1.3  | -    | μA   |
|   |                        | T <sub>A</sub> = 125 °C |                | 1.2  | -    | mA   |
|   | V <sub>R</sub> = 150 V | T <sub>A</sub> = 25 °C  |                | -    | 150  | μA   |
|   | $v_{\rm R} = 150$ V    | T <sub>A</sub> = 125 °C |                | 3    | 15   | mA   |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

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VB10150S-M3

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| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                 |          |      |  |
|--|-----------------|----------|------|--|
| PARAMETER  | SYMBOL          | VB10150S | UNIT |  |
| Typical thermal resistance   | $R_{\theta JC}$ | 2.0      | °C/W |  |

| ORDERING INFORMATION (Example) |                |                 |              |               |               |  |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE                        | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |
| TO-263AB                       | VB10150S-M3/4W | 1.37            | 4W           | 50/tube       | Tube          |  |
| TO-263AB                       | VB10150S-M3/8W | 1.37            | 8W           | 800/reel      | Tape and reel |  |

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

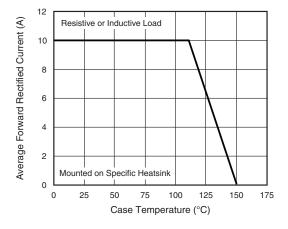


Fig. 1 - Maximum Forward Current Derating Curve

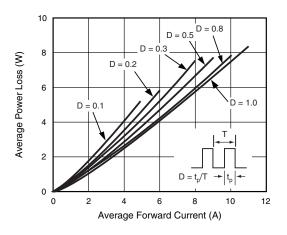


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

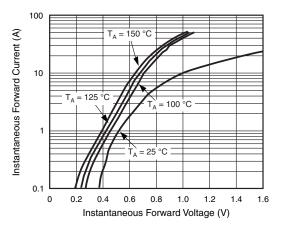


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

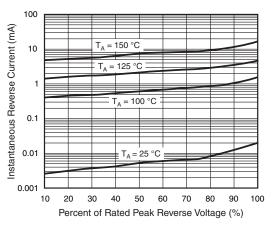
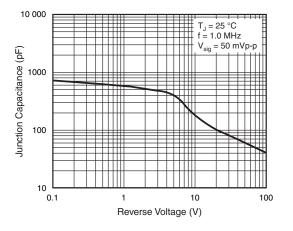


Fig. 4 - Typical Reverse Characteristics Per Diode

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Fig. 5 - Typical Junction Capacitance Per Diode

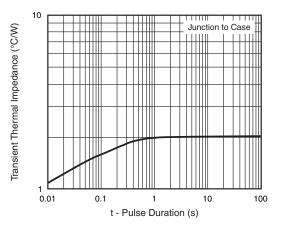
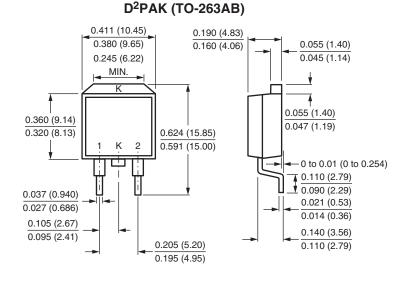
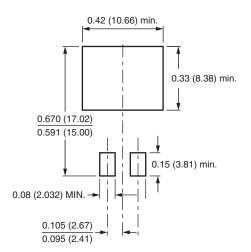


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



### **Mounting Pad Layout**





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